M agnetic eld induced polarization e ects in intrinsically granular superconductors

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(revised version; October 28, 2021)

Based on the previously suggested model of nanoscale dislocations induced Josephson junctions and their arrays, we study the magnetic eld induced electric polarization electric in intrinsically granular superconductors. In addition to a new phenomenon of them om agnetoelectricity, the model predicts also a few other interesting elects, including charge analogues of Meissner paramagnetism (at low elds) and "shtail" anomaly (at high elds). The conditions under which these elects can be experimentally measured in non-stoichiometric high- $T_{\rm c}$ superconductors are discussed.

I. IN TRODUCTION

Both granular superconductors and articially prepared arrays of Josephson junctions (JJAs) proved useful in studying the num erous quantum (charging) e ects in these interesting systems, including blockade of Cooper pair tunneling [1], Bloch oscillations [2], propagation of quantum ballistic vortices [3], spin-tunneling related e ects using specially designed SFS-type junctions [4,5], novelCoulombe ects in SIN IS-type nanoscale junctions [6], and recently observed geometric quantization phenomena [7] (see, e.g., Ref. [8] for the recent review on charge and spin e ects in mesoscopic 2D Josephson junctions).

M ore recently, it was realized that JJAs can be also used as quantum channels to transfer quantum information between distant sites [9{11] through the implementation of the so-called superconducting qubits which take advantage of both charge and phase degrees of freedom (see, e.g., Ref. [12] for a review on quantum-state engineering with Josephson-junction devices).

At the same time, imaging of the granular structure in underdoped B i_2 S r_2 C aC u_2 O $_{8+}$ crystals [13], revealed an apparent charge segregation of its electronic structure into superconducting domains (of the order of a few nanom eters) located in an electronically distinct background. In particular, it was found that at low levels of hole doping (0.2), the holes become concentrated at certain hole-rich domains. Tunneling between such domains leads to intrinsic granular superconductivity (GS) in high- T_c superconductors (HTS). As was shown earlier [14], GS based phenomena can shed some light on the origin and evolution of the so-called param agnetic Meissner elect (PME) which manifests itself both in high- T_c and conventional superconductors [15,16].

In this paper, within a previously suggested [14] model of JJAs created by a regular 2D network of twin-boundary (TB) dislocations with strain elds acting as an insulating barrier between hole-rich domains in underdoped crystals, we address yet another class of interesting phenomena which are actually dual to the chemomagnetice ects described in Ref. [14]. Specifically, we discuss a possible existence of a non-zero electric polarization P (B;) (chemomagnetoelectric ect) and the related change of the charge balance in intrinsically granular non-stoichiometric material under the in uence of an applied magnetic eld. In particular, we predict an anomalous low – eld magnetic behavior of the ective junction charge Q (B;) and concomitant magnetocapacitance C (B;) in paramagnetic Meissner phase and a charge analog of "shtail"-like anomaly at high magnetic elds.

II.THE MODEL

Recall that the observed [13,17{20}] in HTS single crystals regular 2D dislocation networks of oxygen depleted regions with the size d_0 of a few Burgers vectors can provide quite a realistic possibility for existence of 2D Josephson network within CuO plane [21,22]. In this regard, it is also important to mention the pioneer works by K haikin and K hlyustikov [23{25}] on twinning-induced superconductivity in dislocated crystals.

At the same time, in underdoped crystals there is a real possibility to facilitate oxygen transport via the so-called osmotic mechanism [14,19,20,26] which relates a local value of the chemical potential (x) = (0) + r x with a

local concentration of point defects as follows $c(x) = e^{-(x) + k_B T}$, and allows us to explicitly incorporate the oxygen deciency parameter into our model by relating it to the excess oxygen concentration of vacancies $c_v = c(0)$ as follows $c_v = 1$. G. A ssum ing the following connection between the variation of mechanical and chemical properties of planar defects, namely $c_v = c_v =$

To describe the in uence of chem om agnetic e ects on charge balance of an intrinsically granular superconductor, we employ a model of 2D overdam ped Josephson junction array which is based on the well-known Hamiltonian

$$H = \sum_{ij}^{X^{N}} J_{ij} (1 \cos_{ij}) + \sum_{ij}^{X^{N}} \frac{c_{i}c_{j}}{2C_{ij}}$$
(1)

and introduces a short-range (nearest-neighbor) interaction between N junctions (which are formed around oxygen-rich superconducting areas with phases $_i$), arranged in a two-dimensional (2D) lattice with coordinates $x_i = (x_i; y_i)$. The areas are separated by oxygen-poor insulating boundaries (created by TB strain elds (x_{ij})) producing a short-range Josephson coupling $J_{ij} = J_0$ ()e $^{jx_{ij}j-d}$. Thus, typically for granular superconductors, the Josephson energy of the array varies exponentially with the distance $x_{ij} = x_i$ x_j between neighboring junctions (with d being an average junction size). As usual, the second term in the rhs of Eq.(1) accounts for Coulomb elds (x_{ij}) will be responsible for dielectric properties of oxygen-depleted regions as well via the $^{-}$ dependent capacitance tensor C_{ij} () = C [(x_{ij})].

If, in addition to the chem ical pressure r(x) = K(x), the network of superconducting grains is under the in uence of an applied frustrating magnetic eld B, the total phase dierence through the contact reads

$$_{ij} = {}^{0}_{ij} + \frac{w}{0} (x_{ij} ^n_{ij}) \quad B + \frac{r}{h};$$
 (2)

where $_{ij}^{0}$ is the initial phase di erence (see below), $n_{ij} = X_{ij} = jX_{ij}$ jw ith $X_{ij} = (x_i + x_j) = 2$, and $w = 2_L(T) + 1$ w ith $_L$ being the London penetration depth of superconducting area and l an insulator thickness (w hich, w ith in the discussed here scenario, is simply equal to the TB thickness [26]).

As usual, to safely neglect the in wence of the self-elde ects in a real material, the corresponding Josephson penetration length $_{\rm J}=\frac{1}{0}$ = $_{\rm 0}$ j_cw must be larger than the junction size d. Here j_c is the critical current density of superconducting (hole-rich) area. As we shall see below, this condition is rather well satisted for HTS single crystals.

III. CHEMOMAGNETOELECTRICITY

In what follows, we shall be interested in the behavior of magnetic eld induced electric polarization (chem om agnetoelectricity) in chem ically induced GS described by a 2D JJA.Recall that a conventional (zero-eld) pair polarization operator within the model under discussion reads [27,28]

$$p = \sum_{i=1}^{X^{i}} q_{i}x_{i}$$
(3)

In view of Eqs.(1)-(3), and taking into account a usual "phase-number" commutation relation, $[i;n_j] = i_{ij}$, it can be shown that the evolution of the pair polarization operator is determined via the equation of motion

$$\frac{\mathrm{dp}}{\mathrm{dt}} = \frac{1}{\mathrm{ih}} \left[p; H \right] = \frac{2e}{h} \int_{\mathrm{ij}}^{X^{N}} J_{\mathrm{ij}} \sin_{\mathrm{ij}} (t) x_{\mathrm{ij}}$$
(4)

Resolving the above equation, we arrive at the following net value of the magnetic-eld induced longitudinal (along x-axis) electric polarization P (;B) < ;B (t) > and the corresponding electric polarization charge

$$Q(;B) = \frac{2eJ_0}{h} \frac{z}{dt} \frac{z^{t}}{dt^{0}} \frac{z}{dt^{0}} \frac{d^{2}x}{s} \sin(x;t^{0}) x e^{-jx j - d};$$
 (5)

where S=2 d^2 is properly de ned from alization area, is a characteristic time (see D iscussion), and we made a usual substitution $\frac{1}{N}$ $_{ij}$ A_{ij} (t) ! $\frac{1}{S}$ d^2xA (x;t) valid in the long-wavelength approximation [28].

To capture the very essence of the superconducting analog of the chem om agnetoelectric e ect, in what follows we assume for simplicity that a stoichiometric sample (with '0) does not possess any spontaneous polarization at zero magnetic eld, that is P (0;0) = 0. A coording to Eq.(5), this condition implies $_{ij}^{0} = 2$ m for the initial phase dierence with m = 0; 1; 2;:..

Taking the applied magnetic eld along the c-axis (and normal to the CuO plane), that is B = (0;0;B), we obtain nally

$$Q(;B) = Q_0()\frac{2b + b(1 - b^2)}{(1 + b^2)(1 + b^2)^2}$$
(6)

for the magnetic eld behavior of the elective junction charge in chemically induced granular superconductors.

Here Q_0 () = e J_0 ()=h with J_0 () de ned earlier, b = B=B₀, \breve{b} = b b, and b = B=B₀' (k_B T =h) where B () = ($_v$ =h)B₀ is the chem ically-induced contribution (which disappears in optimally doped systems with '0), and B₀ = $_0$ =w d is a characteristic Josephson eld.

Fig.1 shows changes of the initial (stoichiom etric) e ective junction charge Q (solid line) with oxygen de ciency. Notice a sign change of Q (dotted and dashed lines) driven by non-zero values of at low magnetic elds (a charge analog of chemically induced PME). According to Eq.(6), the elective charge changes its sign as soon as the chemical operation of the contribution B () exceeds an applied magnetic eld B (see D iscussion).

At the sam etim e, Fig 2 presents a true chem celectric e ect with concentration (de ciency) induced e ective junction charge Q (;0) in zero magnetic eld. Notice that Q (;0) exhibits a maximum around $_{\rm c}$ ' 02 (in agreement with the classical percolative behavior observed in non-stoichiometric YB a₂C u₃O₇ samples [17]).

It is of interest also to consider the magnetic eld behavior of the concommitant elective ux capacitance C dQ (;B)=d which in view of Eq.(6) reads

$$C(;B) = C_0()\frac{1 - 3bb - 3b^2 + bb^3}{(1 + b^2)(1 + b^2)^3};$$
(7)

where = SB, and C $_0$ () = Q_0 ()= $_0$.

Fig.3 depicts the behavior of the elective ux capacitance C(B) in applied magnetic eld for dierent values of oxygen deciency parameter: '0 (solid line), = 0:1 (dashed line), and = 0:2 (dotted line). Notice a decrease of magnetocapacitance amplitude and its peak shifting with increase of and sign change at low magnetic elds which is another manifestation of the charge analog of chemically induced PME (Cf. Fig.1).

IV.CHARGE ANALOG OF "FISHTAIL" ANOMALY

So far, we neglected a possible eld dependence of the chem ical potential $_{\rm V}$ of oxygen vacancies. Recall, however, that in high enough applied magnetic elds B, the eld-induced change of the chem ical potential $_{\rm V}$ (B) $_{\rm V}$ (B) $_{\rm V}$ (O) become stangible and should be taken into account [14,29,30]. As a result, we end up with a superconducting analog of the so-called magnetoconcentration e ect [14] with eld induced creation of oxygen vacancies $c_{\rm V}$ (B) = $c_{\rm V}$ (O) exp ($_{\rm V}$ (B)= $k_{\rm B}$ T) which in turn brings about a "shtail"-like behavior of the high-eld chem om agnetization (see Ref. [14] for more details).

Fig.4 shows the eld behavior of the elective junction charge in the presence of the above-mentioned magnetoconcentration elect. As it is clearly seen, Q(B); B) exhibits a "shtail"-like anomaly typical for previously discussed [14] chem om agnetization in underdoped crystals with intragrain granularity (for symmetry and better visuale ective also plotted Q(B); B) in the same gure). This more complex structure of the elective charge appears when the applied magnetic eld B matches an intrinsic chem om agnetic eld B (B)) (which now also depends on B via the magnetoconcentration election. Notice that a "shtail" structure of Q(B); B) manifests itself even at zero values of

eld-free de ciency parameter (0) (solid line in Fig.4) thus con rm ing a eld-induced nature of intrinsic granularity [13,17{20}]. Likewise, Fig.5 depicts the evolution of the elective ux capacitance C ((B); (B)) in applied magnetic eld (B) in the presence of magnetoconcentration elective ux capacitance C ((B); (B)) in applied magnetic eld (B) in the presence of magnetoconcentration elective ux capacitance C ((B); (B)) in applied magnetic

V.D ISCUSSION

Thus, the present model predicts appearance of two interrelated phenomena (dual to the previously discussed behavior of chemom agnetizm [14]), namely a charge analog of Meissner paramagnetism at lowelds and a charge analog of shtail anomaly at highelds. To see whether these elects can be actually observed in a real material, let us estimate an order of magnitude of the main model parameters.

U sing typical [17,19] for HTS single crystals values of $_{\rm L}$ (0) ' 150nm , d' 10nm , and j ' $_{\rm L}$ ' $_{\rm L}$ 10^10 A =m ², we arrive at the following estimates of the characteristic B $_{\rm 0}$ ' 0:5T and chemomagnetic B () ' 0:5B $_{\rm 0}$ elds, respectively. So, the predicted charge analog of PME should be observable for applied magnetic elds B < 0.25T . Notice that, for the above set of parameters, the Josephson length is of the order of $_{\rm J}$ ' 1 m, which means that the assumed in this paper small-junction approximation is valid and the "self-eld" elects can be safely neglected.

Furtherm ore, the characteristic frequencies! $^{\prime}$ needed to probe the suggested here e ects are related to the processes governed by tunneling relaxation times $^{\prime}$ h=J₀(). Since for oxygen deciency parameter = 0:1 the chem ically-induced zero-tem perature Josephson energy in non-stoichiom etric YBCO single crystals is of the order of J₀() $^{\prime}$ k_B T_C $^{\prime}$ 1m eV, we arrive at the required frequencies of! $^{\prime}$ 10¹³Hz and at the following estimates of the elective junction charge Q₀ $^{\prime}$ e = 1:6 10 ¹⁹C and ux capacitance C₀ $^{\prime}$ 10 ¹⁸F. Notice that the above estimates fall into the range of parameters used in typical experiments for studying the single-electron tunneling elects both in JJs and JJAs [1,2,12,31] suggesting thus quite an optimistic possibility to observe the above-predicted eld induced elects experimentally in non-stoichiometric superconductors with pronounced networks of planar defects or in articially prepared JJAs. (It is worth mentioning that a somewhat similar behavior of the magnetic eld induced charge and related ux capacitance has been observed in 2D electron systems [32].)

And nally, it can be easily veri ed that, in view of Eqs.(1)-(5), the eld-induced Coulomb energy of the oxygen-depleted region within our model is given by

$$E_{C}(;B) \xrightarrow{*} \frac{x^{N}}{2C_{ij}} \xrightarrow{q_{i}q_{j}} = \frac{Q^{2}(;B)}{2C(;B)}$$
(8)

with Q (;B) and C (;B) de ned by Eqs. (6) and (7), respectively.

A thorough analysis of the above expression reveals that in the PME state (when B B) the chemically-induced granular superconductor is always in the so-called C oulomb blockade regime (with E $_{\text{C}} > J_{0}$), while in the "shtail" state (for B B) the energy balance tips in favor of tunneling (with E $_{\text{C}} < J_{0}$). In particular, E $_{\text{C}}$ (;B = 0:1B) = $_{\overline{2}}J_{0}$ () and E $_{\text{C}}$ (;B = B) = $_{\overline{8}}J_{0}$ (). It would be also interesting to check this phenomenon of eld-induced weakening of the C oulomb blockade experimentally.

VI.CONCLUSION

In conclusion, within a realistic model of 2D Josephson junction arrays created by 2D network of twin boundary dislocations (with strain elds acting as an insulating barrier between hole-rich domains in underdoped crystals), a few novel electric polarization related e ects expected to occur in intrinsically granular material under applied magnetic elds were predicted, including a phenomenon of them om agnetoelectricity, an anomalous low – eld magnetic behavior of the electric junction charge (and ux capacitance) in paramagnetic Meissner phase and a charge analog of "shtail"-like anomaly at high magnetic elds as well as eld-dependent weakening of the chemically-induced Coulomb blockade. The experimental conditions needed to observe the predicted here elects in non-stoichiometric high-T_c superconductors were discussed.

ACKNOW LEDGMENTS

This work was done during my stay at the Center for Physics of Fundam ental Interactions (Instituto Superior Tecnico, Lisbon) and was partially funded by the FCT. I thank Pedro Sacram ento and Vitor Vieira for hospitality

and interesting discussions on the subject. I am also indebted to the Referee for drawing my attention to the pioneer works by K haikin and K hlyustikov on twinning-induced superconductivity in dislocated crystals.

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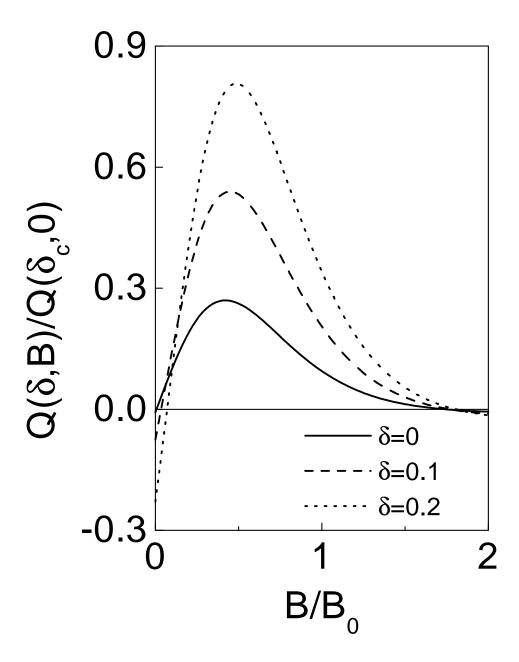


FIG.1. The elective junction charge Q (;B)=Q (c;0) (chem om agnetoelectric electric electric

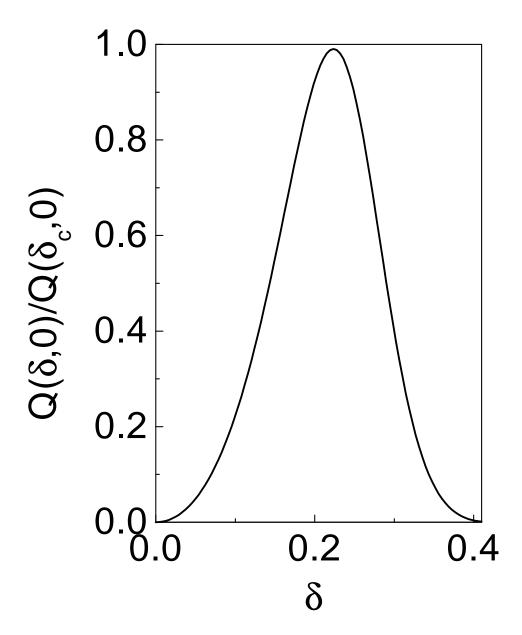


FIG.2. Chem ically induced e ective junction charge Q (;0)=Q ($_{c}$;0) in a zero applied magnetic eld (true chem oelectric e ect).

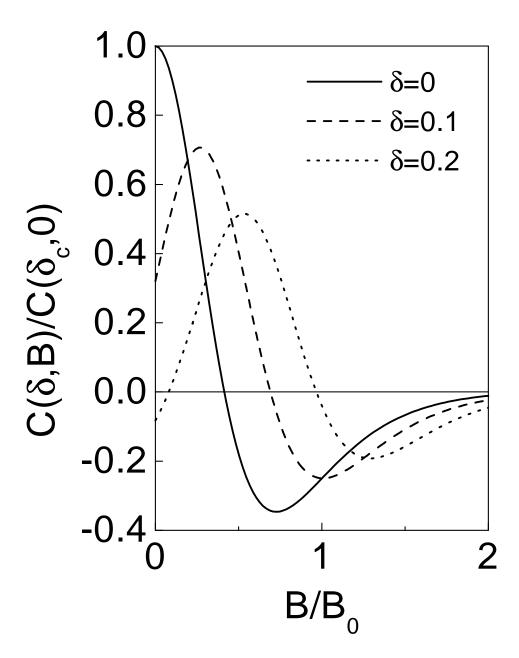


FIG.3. The elective ux capacitance C (;B)=C ($_{c}$;0) as a function of applied magnetic eld B=B $_{0}$, according to Eq.(7), for dierent values of oxygen deciency parameter: '0 (solid line), = 0:1 (dashed line), and = 0:2 (dotted line).

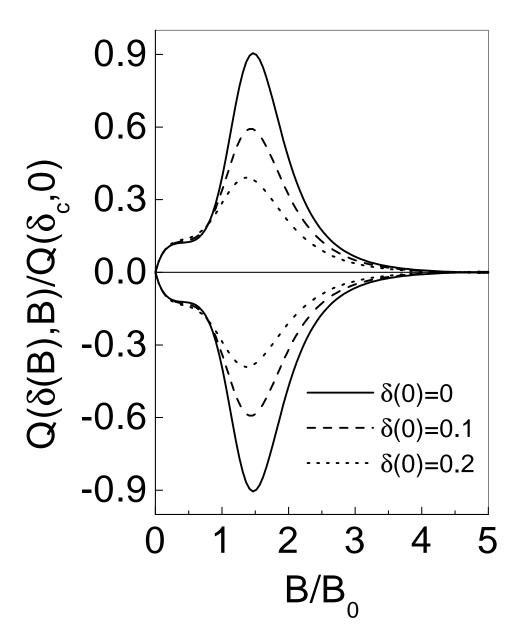


FIG. 4. A " shtail"-like behavior of e ective charge Q ((B);B)=Q ($_c;0$) in applied magnetic eld $B=B_0$ in the presence of magnetoconcentration e ect (with eld-induced oxygen vacancies (B)) for three values of eld-free de ciency parameter: (0) ' 0 (solid line), (0) = 0.1 (dashed line), and (0) = 0.2 (dotted line).

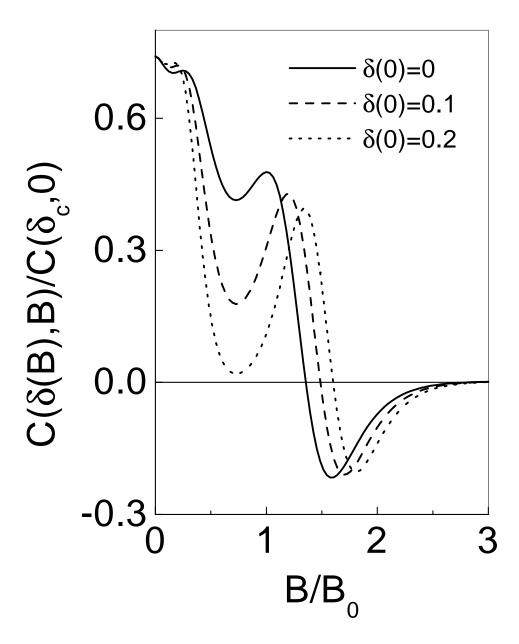


FIG.5. The behavior of the elective ux capacitance C ((B);B)=C ($_{\rm c}$;0) in applied magnetic eld B=B $_{\rm 0}$ in the presence of magnetoconcentration elect for three values of eld-free deciency parameter: (0) '0 (solid line), (0) = 0:1 (dashed line), and (0) = 0:2 (dotted line).